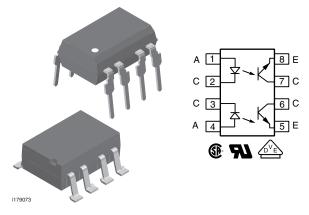


Vishay Semiconductors

Optocoupler, Phototransistor Output, Dual Channel



DESCRIPTION

The MCT6 is a two channel optocoupler for high density applications. Each channel consists of an optically coupled pair with a gallium arsenide infrared LED and a silicon NPN phototransistor. Signal information, including a DC level, can be transmitted by the device while maintaining a high degree of electrical isolation between input and output.

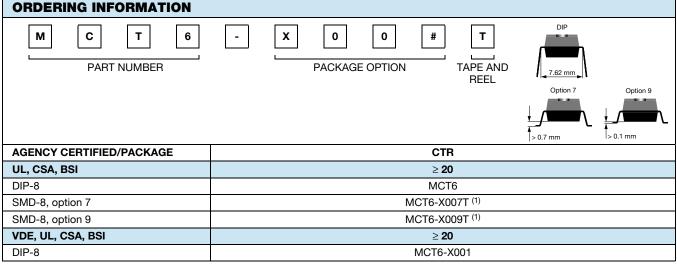
The MCT6 is especially designed for driving medium-speed logic, where it may be used to eliminate troublesome ground loop and noise problems. It can also be used to replace relays and transformers in many digital interface applications, as well as analog applications such as CRT modulation.

FEATURES

- Current transfer ratio, 50 % typical
- Leakage current, 1.0 nA typical
- Two isolated channels per package
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

AGENCY APPROVALS

- UL1577, file no. E52744 system code H, double protection
- cUL tested to CSA 22.2 bulletin 5A
- DIN EN 60747-5-5 (VDE 0884-5), available with option 1
- CSA 93751
- BSI EN 60950, BSI EN 60065



Notes

· Additional options may be possible, please contact sales office

⁽¹⁾ Also available in tubes, do not put "T" on the end



RoHS

COMPLIANT



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MCT6

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
INPUT						
Rated forward current, DC			60	mA		
Peak forward current, DC	1.0 µs pulse, 300 pps	I _{FM}	3.0	A		
Power dissipation		P _{diss}	100	mW		
Derate linearly from 25 °C			1.3	mW/°C		
OUTPUT	•	-		•		
Collector current		Ι _C	30	mA		
Collector emitter breakdown voltage		BV _{CEO}	30	V		
Power dissipation		P _{diss}	150	mW		
Derate linearly from 25 °C			2.0	mW/°C		
COUPLER						
Total package dissipation		P _{tot}	400	mW		
Derate linearly from 25 °C			5.33	mW/°C		
Storage temperature		T _{stg}	-55 to +150	°C		
Operating temperature		T _{amb}	-55 to +100	°C		
Lead soldering time at 260 °C			10	S		

Note

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
INPUT								
Forward voltage	I _F = 20 mA	V _F		1.25	1.50	V		
Reverse current	V _R = 3.0 V	I _R		0.1	10	μA		
Junction capacitance	V _F = 0 V	Cj		25		pF		
OUTPUT	OUTPUT							
Collector emitter breakdown voltage	$I_{C} = 1.0 \ \mu A, I_{E} = 10 \ \mu A$	BV _{CEO}	30	65		V		
Emitter collector breakdown voltage	$I_{C} = 10 \ \mu A, I_{E} = 10 \ \mu A$	BV _{ECO}	7.0	10		V		
Collector emitter leakage current	V _{CE} = 10 V	I _{CEO}		1.0	100	nA		
Collector emitter capacitance	$V_{CE} = 0 V$	C _{CE}		8.0		pF		
COUPLER								
Saturation voltage, collector emitter	$I_{C} = 2.0 \text{ mA}, I_{F} = 16 \text{ mA}$	V _{CEsat}			0.40	V		
Capacitance (input to output)	f = 1.0 MHz	C _{IO}		0.5		pF		
Capacitance between channels	f = 1.0 MHz			0.4		pF		
Bandwidth	$I_{C} = 2.0 \text{ mA}, \text{V}_{CC} = 10 \text{ V}, \\ \text{R}_{L} = 100 \Omega$			150		kHz		

Note

 Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
DC current transfer ratio	$I_{F} = 10 \text{ mA}, V_{CE} = 10 \text{ V}$	CTR _{DC}	20	50		%

SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION SYMBOL MIN. TYP. MAX. UN					
Switching times, output transistor	I_C = 2.0 mA, R_L = 100 Ω,V_{CE} = 5 V	t _{on} , t _{off}		3.0		μs

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SAFETY AND INSULATION RATINGS						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Climatic classification	According to IEC 68 part 1		55/100/21			
Comparative tracking index		CTI	175			
Maximum rated withstanding isolation voltage	t = 1 min	V _{ISO}	4420	V _{RMS}		
Maximum transient isolation voltage		VIOTM	10 000	V _{peak}		
Maximum repetitive peak isolation voltage		V _{IORM}	890	V _{peak}		
Isolation resistance	$V_{IO} = 500 \text{ V}, \text{ T}_{amb} = 25 ^{\circ}\text{C}$	R _{IO}	≥ 10 ¹²	Ω		
	$V_{IO} = 500 \text{ V}, \text{ T}_{amb} = 100 ^{\circ}\text{C}$	R _{IO}	≥ 10 ¹¹	Ω		
Output safety power		P _{SO}	400	mW		
Input safety current		I _{SI}	275	mA		
Safety temperature		T _S	175	°C		
Creepage distance			≥7	mm		
Clearance distance			≥7	mm		
Insulation thickness		DTI	≥ 0.4	mm		

Note

• As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

LED Current

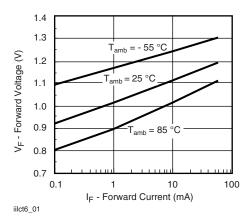


Fig. 1 - Forward Voltage vs. Forward Current

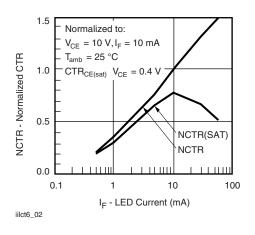


Fig. 2 - Normalized Non-Saturated and Saturated CTR vs.

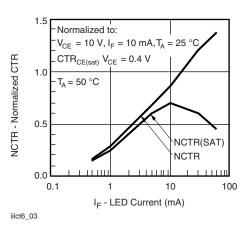
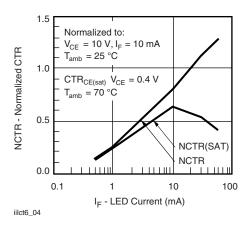


Fig. 3 - Normalized Non-Saturated and Saturated CTR vs. LED Current



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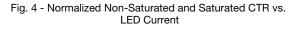
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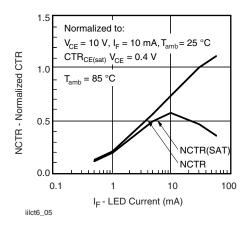


Fig. 5 - Normalized Non-Saturated and Saturated CTR vs. LED Current

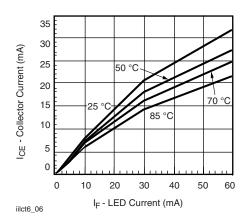


Fig. 6 - Collector Emitter Current vs. Temperature and LED Current

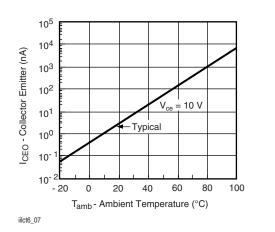


Fig. 7 - Collector Emitter Leakage Current vs.Temperature

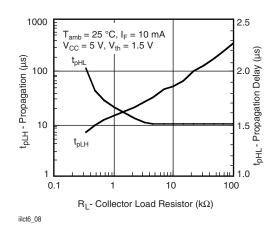


Fig. 8 - Propagation Delay vs. Collector Load Resistor

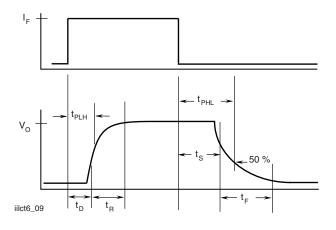


Fig. 9 - Switching Timing

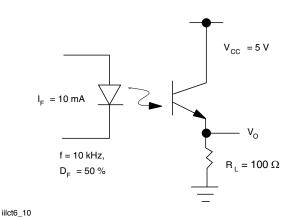


Fig. 10 - Switching Schematic



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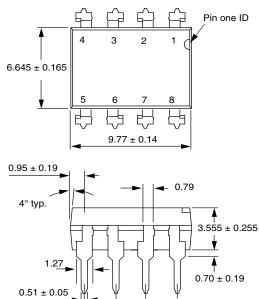


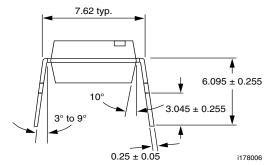
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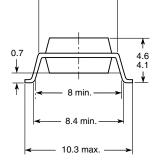
PACKAGE DIMENSIONS in millimeters

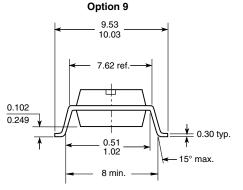




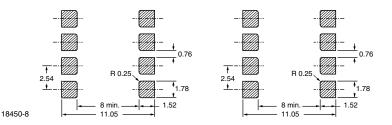


2.54 typ.

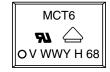




ISO method A



PACKAGE MARKING



Notes

- Only options 1 and 7 reflected in the package marking
- The VDE logo is only marked on option 1 parts
- Tape and reel suffix (T) is not part of the package marking

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